

# Quantum<sup>™</sup> SA.45s CSAC

Chip Scale Atomic Clock



#### **Key Features**

- Power consumption <120 mW
- Less than 17 cc volume, 1.6" x 1.39" x 0.45"
- 10 MHz CMOS-compatible output
- 1 PPS output and 1 PPS input for synchronization
- RS-232 interface for monitoring and control
- Short term stability (Allan Deviation) of 2.5E-10@ TAU =1 sec

### Applications\*

- Underwater sensor systems
- GPS receivers
- Backpack radios
- Anti-IED jamming systems
- Autonomous sensor networks
- Unmanned vehicles

\*The Chip Scale Atomic Clock is not tested, qualified, and rated for space applications.

With an extremely low power consumption of <120 mW and a volume of <17 cc, the Microsemi® SA.45s Chip Scale Atomic Clock (CSAC) brings the accuracy and stability of an atomic clock to portable applications for the first time.

The SA.45s provides 10 MHz and 1 PPS outputs at standard CMOS levels, with short-term stability (Allan Deviation) of 2.5E-10 @ TAU =1 sec, long-term aging of <9E-10/month, and maximum frequency change of 5E-10 over an operating temperature range of -10°C to +35°C.

The SA.45s CSAC accepts a 1 PPS input that may be used to synchronize the unit's 1 PPS output to an external reference clock with ±100 ns accuracy. The CSAC can also use the 1 PPS input to discipline its phase and frequency to within 1 ns and 1.0E-12, respectively.

A standard CMOS-level RS-232 serial interface is built in to the SA.45s. This is used to control and calibrate the unit and also to provide a comprehensive set of status monitors. The interface is also used to set and read the CSAC's internal time-of-day clock.



Microsemi invented portable atomic timekeeping with QUANTUM™, the world's first family of miniature and chip scale atomic clocks.

Choose QUANTUM™ class for best-in-class stability, Size, Weight and Power consumption (SWAP).



# Quantum™ SA.45s CSAC

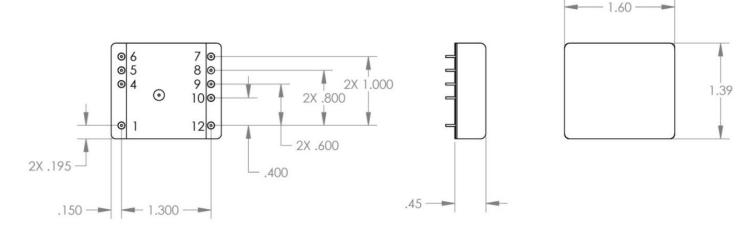
# Options to Meet a Wider Range of Applications

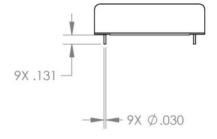
The standard SA.45s CSAC option 001 provides an output frequency of 10MHz. However, other output frequencies are available: option 003 provides 16.384 MHz, and option 004 provides 10.24 MHz and option 006 provides a 5 MHz output.

For other output frequencies please contact Microsemi for details.

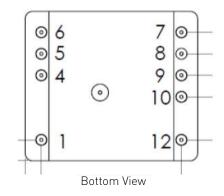
The Chip Scale Atomic Clock is not tested, qualified, and rated for space applications.

#### **Mechanical Interface**





PIN NO.	I.D.
1	Tune
2	N/A
3	N/A
4	BITE
5	Tx
6	Rx
7	Vcc
8	GND
9	1 PPS IN
10	1 PPS OUT
11	N/A
12	10 MHz OUT





# Power Matters.™

# Quantum<sup>™</sup> SA.45s CSAC Option 001

Part number 090-00218-001

# **Specifications**

All specifications at 25°C, Vcc = 3.3V DC unless otherwise specified

#### **ELECTRICAL SPECIFICATIONS**

**RF Output** 

- Frequency: 10 MHz
- Format: CMOS
- Amplitude: 0V to Vcc
- Load impedance: 1 MΩ
- Quantity: 1

#### 1 PPS Output

- Rise/fall time (10%-90%)

at load capacitance 10pF: <10 ns
- Pulse width: 100 µs
- Level: 0V to Vcc
- Logic High (VoH) min: 2.80 V
- Logic Low (VoL) max: 0.30 V
- Load impedance: 1 MΩ
- Quantity: 1

#### 1 PPS Input

 $\begin{array}{lll} \text{- Format:} & \text{Rising edge} \\ \text{- Low level:} & <0.5 \text{ V} \\ \text{- High level:} & 2.5 \text{ V to Vcc} \\ \text{- Input impedance:} & 1 \text{ M}\Omega \\ \text{- Quantity:} & 1 \end{array}$ 

#### **Serial Communications**

- Protocol: RS232
- Format: CMOS 0V to Vcc
- Tx/Rx impedance: 1 MΩ
- Baud rate: 57600

# Built-in Test Equipment (BITE) output

- Format: CMOS 0V to Vcc

- Load impedance:  $1 M\Omega$ 

- Logic: 0 = Normal operation

1 = Alarm

# Power Input

- Operating: <120 mW - Warmup: <140 mW - Input voltage (Vcc): 3.3 ± 0.1 VDC

#### PHYSICAL SPECIFICATIONS

- Size: 1.6" x 1.39" x 0.45"

- Weight: <35 g - MTBF: >100,000 hours

#### **ENVIRONMENTAL SPECIFICATIONS**

Operating:

- Operating temperature: -10°C to +35°C

- Maximum frequency change over operating temp range (max. rate of change

(max. rate of change 0.5 °C/minute): ±5x10<sup>-10</sup>

- Frequency change over allowable input

voltage range:  $\pm 4x10^{-10}$ 

#### **ENVIRONMENTAL SPECIFICATIONS (Continued)**

- Magnetic sensitivity

(≼2.0 Gauss): ±9x10-11/Gauss
- Radiated emissions. Compliant to FCC

part 15, Class B, when mounted properly onto host PCB.

- Vibration: Maintains lock under

MIL-STD-810, Method 514.5, Procedure 1, 7.7 grms 0 to 95% RH per

- Humidity: 0 to 95% RH pe MIL-STD-810,

Method 507.4.

Storage and Transport (non-operating):

- Temperature: -55°C to +40°C
- Shock (1 ms half-sine): 1000 g
- Vibration: MIL-STD-810, Method 514.5, Procedure 1, 7.7 grms

#### PERFORMANCE PARAMETERS

#### Stability (Allan Deviation)

ADEV

### RF Output Phase Noise (SSB)

1 Hz <-50 dBc/Hz 10 Hz <-70 dBc/Hz 100 Hz <-113 dBc/Hz 1000 Hz <-128 dBc/Hz 10000 Hz <-135 dBc/Hz 100,000 Hz <-140 dBc/Hz

# Frequency Accuracy

- Maximum offset at shipment: ±5x10<sup>-11</sup>
- Maximum retrace (48 hrs off): ±5x10<sup>-10</sup>
- Aging, monthly\*: <9x10<sup>-10</sup> typical
- Aging, yearly\*: <1x10<sup>-8</sup> typical
- 1 PPS Sync.: ±100 ns
(\*After 30 days of continuous operation)

#### Digital Tuning

- Range:  $\pm 2x10^{-8}$ - Resolution:  $1x10^{-12}$ 

#### **Analog Tuning**

- Range:  $\pm 2.2 \times 10^{-8}$ - Resolution:  $1 \times 10^{-11}$ 

- Input:  $ext{ 0-2.5V into } 100 \text{ k}\Omega$ 

Warm-up Time <180 s

#### Solder

Hand solder using 63/37 Tin/Lead Solder with maximum soldering tip of 329°C (625°F)



# Power Matters.™

# Quantum<sup>™</sup> SA.45s CSAC Option 003

Part number 090-00218-003

# **Specifications**

All specifications at 25°C, Vcc = 3.3V DC unless otherwise specified

#### **ELECTRICAL SPECIFICATIONS**

- Frequency:	16.384 MH:
- Format:	CMOS
- Amplitude:	0V to Vcc
- Load impedance:	1 ΜΩ
- Quantity:	1

#### 1 PPS Output

1 PPS Output	
- Rise/fall time (10%-90%)	
at load capacitance 10pF:	<10 ns
- Pulse width:	97.656 µs
- Level:	0V to Vcc
- Logic High (VOH) min:	2.80 V
- Logic Low (VOL) max:	0.30 V
- Load impedance:	1 ΜΩ
- Quantity:	1

#### 1 PPS Input

- Format:	Rising edge
- Low level:	<0.5 V
- High level:	2.5 V to Vcc
- Input impedance:	1 ΜΩ
- Quantity:	1

## Serial Communications

- Protocol:	RS-232
- Format:	CMOS 0V to Vcc
- Tx/Rx impedance:	1 ΜΩ
- Baud rate:	57600

# Built-in Test Equipment (BITE) output

- Format:	CMOS 0V to Vcc
- Load impedance:	1 ΜΩ
- Logic:	0 = Normal operation 1 = Alarm

#### **Power Input**

- Operating:	<120 mW
- Warmup:	<140 mW
- Input Voltage (Vcc):	$3.3 \pm 0.1  VDC$

#### PHYSICAL SPECIFICATIONS

- Size:	1.6" x 1.39" x 0.45"
- Weight:	<35 g
- MTBF:	>100,000 hours

#### **ENVIRONMENTAL SPECIFICATIONS**

#### Operating:

- Op	erating	temperatur	re:	-10°C to +35°C
		_		

- Maximum frequency char	ge
over operating temp rang	е
(max. rate of change	
0.5°C/minute):	

.5°C/minute): ±5x10<sup>-10</sup>

- Frequency change over allowable input

voltage range:  $\pm 4x10^{-10}$ 

# ENVIRONMENTAL SPECIFICATIONS (Continued)

- Magnetic sensitivity (<2.0 Gauss):	±9x10 <sup>-11</sup> /Gauss
- Radiated emissions:	Compliant to FCC part 15, Class B, when mounted properly onto host PCB
- Vibration:	Maintains lock under MIL-STD-810, method 514.5, procedure 1, 7.7 grms

7.7 grms 0 to 95% RH per MIL-STD-810, method 507.4

7.7 grms

#### Storage and Transport (non-operating):

- Temperature:	-55°C to +40°C
- Shock (1 ms half-sine):	1000 g
- Vibration:	MIL-STD-810, meth
	514.5. procedure 1.

#### PERFORMANCE PARAMETERS

#### Stability (Allan Deviation)

#### **ADEV**

- Humidity:

TAU = 1 sec	2.5x10 <sup>-10</sup>
TAU = 10 sec	8x10 <sup>-11</sup>
TAU = 100 sec	2.5x10 <sup>-11</sup>
TAU = 1000 sec	8x10 <sup>-12</sup>

## RF Output Phase Noise (SSB)

1 Hz	<-46 dBc/Hz
10 Hz	<-66 dBc/Hz
100 Hz	<-110 dBc/Hz
1000 Hz	<-128 dBc/Hz
10000 Hz	<-135 dBc/Hz
100,000 Hz	<-140 dBc/Hz

#### Frequency Accuracy

. , ,	
- Maximum offset at shipmen	t: ±5x10 <sup>-11</sup>
- Maximum retrace (48 hrs of	f): ±5x10 <sup>-10</sup>
- Aging, monthly*:	<9x10 <sup>-10</sup> typica
- Aging, yearly*:	<1x10 <sup>-8</sup> typical
- 1 PPS Sync.:	±100 ns

(\*After 30 days of continuous operation)

## **Digital Tuning**

- Range:	±2x10 <sup>-8</sup>
- Resolution:	1x10 <sup>-12</sup>

#### **Analog Tuning**

- Range:	±2.2x10 <sup>-8</sup>
- Resolution:	1x10 <sup>-11</sup>
Innut.	0.2 5V into 100 k0

- Input: \$0--2.5V\$ into  $100~k\Omega$ 

Warm-up Time <180 s

#### Solder

Hand solder using 63/37 Tin/Lead Solder with maximum soldering tip of 329°C (625°F)



# Quantum<sup>™</sup> SA.45s CSAC Option 004

Part number 090-00218-004

# **Specifications**

All specifications at 25°C, Vcc = 3.3V DC unless otherwise specified

#### **ELECTRICAL SPECIFICATIONS**

#### **RF Output**

- Frequency:	10.24 MHz
- Format:	CMOS
- Amplitude:	0V to Vcc
- Load impedance:	1 ΜΩ
- Quantity:	1

#### 1 PPS Output

- Rise/fall time (10%-90%)	
at load capacitance 10pF:	<10 ns
- Pulse width:	100 µs
- Level:	0V to Vcc
- Logic High (VOH) min:	2.80 V
- Logic Low (VOL) max:	0.30 V
- Load impedance:	1 ΜΩ
- Quantity:	1

#### 1 PPS Input

- Format:	Rising edge
- Low level:	<0.5 V
- High level:	2.5 V to Vcc
- Input impedance:	1 ΜΩ
- Quantity:	1

#### **Serial Communications**

- Protocol:	RS-232
- Format:	CMOS 0V to Vcc
- Tx/Rx impedance:	1 ΜΩ
- Baud rate:	57600

#### Built-in Test Equipment (BITE) output

- Format:	CMOS 0V to Vcc
- Load impedance:	1 ΜΩ
- Logic:	0 = Normal operation 1 = Alarm

# **Power Input**

- Operating:	<120 mW
- Warmup:	<140 mW
- Input Voltage (Vcc):	$3.3 \pm 0.1  \text{VDC}$

# **PHYSICAL SPECIFICATIONS**

- Size:	1.6" x 1.39" x 0.45"
- Weight:	<35 g
- MTRF	>100 000 hours

#### **ENVIRONMENTAL SPECIFICATIONS**

### Operating:

- Uperating temperature:	-10°C to +35°C
- Maximum frequency change	

over operating temp range (max. rate of change

±5x10<sup>-10</sup> 0.5°C/minute):

- Frequency change over allowable input

±4x10<sup>-10</sup> voltage range:

#### ENVIRONMENTAL SPECIFICATIONS (Continued)

- Magnetic sensitivity (≤2.0 Gauss): ±9x10<sup>-11</sup>/Gauss - Radiated emissions: Compliant to FCC part 15, Class B, when mounted properly onto host PCB

- Vibration: Maintains lock under MIL-STD-810, method 514.5, procedure 1, 7.7 grms

0 to 95% RH per MIL-

- Humidity: STD-810, method 507.4

#### Storage and Transport (non-operating):

- Temperature:	-55°C to +40°C
- Shock (1 ms half-sine):	1000 g
- Vibration:	MIL-STD-810, meth

#### 514.5, procedure 1, 7.7 grms

# PERFORMANCE PARAMETERS

#### Stability (Allan Deviation)

#### **ADEV**

TAU = 1 sec	2.5x10 <sup>-10</sup>
TAU = 10 sec	8x10 <sup>-11</sup>
TAU = 100 sec	2.5x10 <sup>-11</sup>
TAU = 1000 sec	8x10 <sup>-12</sup>

#### RF Output Phase Noise (SSB)

1 Hz	<-50 dBc/Hz
10 Hz	<-70 dBc/Hz
100 Hz	<-113 dBc/Hz
1000 Hz	<-128 dBc/Hz
10000 Hz	<-135 dBc/Hz
100 000 Hz	<-140 dBc/Hz

### Frequency Accuracy

- Maximum offset at shipment:	±5x10 <sup>-11</sup>
- Maximum retrace (48 hrs off):	±5x10 <sup>-10</sup>
- Aging, monthly*:	<9x10 <sup>-10</sup> typical
- Aging, yearly*:	<1x10 <sup>-8</sup> typical
- 1 PPS Sync.:	±100 ns

(\*After 30 days of continuous operation)

### **Digital Tuning**

- Range:	±2x10 <sup>-8</sup>
- Resolution:	1x10 <sup>-12</sup>

#### **Analog Tuning**

- Range:	±2.2x10 <sup>-8</sup>
- Resolution:	1x10 <sup>-11</sup>
	0.051/: . 4001.0

0-2.5V into 100  $k\Omega$ - Input:

Warm-up Time < 180 s

Hand solder using 63/37 Tin/Lead Solder with maximum soldering tip of 329°C (625°F)



# Power Matters.™

# Quantum™ SA.45s CSAC Option 006

Part number 090-00218-006

# **Specifications**

All specifications at 25°C, Vcc = 3.3V DC unless otherwise specified

#### **ELECTRICAL SPECIFICATIONS**

#### **RF Outptut**

- Frequency:	5 MHz
- Format:	CMOS
- Amplitude:	0V to Vcc
- Load impedance:	1 ΜΩ
- Quantity:	1

#### 1 PPS Output

- Rise/fall time (10%-90%)	
at load capacitance 10pF:	<10 ns
- Pulse width:	100 µs
- Level:	0V to Vcc
- Logic High (VOH) min:	2.80 V
- Logic Low (VOL) max:	0.30 V
- Load impedance:	1 ΜΩ
- Quantity:	1

#### 1 PPS Input

- Format:	Rising edge
- Low level:	<0.5 V
- High level:	2.5 V to Vcc
- Input impedance:	1 ΜΩ
- Quantity:	1

#### **Serial Communications**

- Protocol:	RS-232
- Format:	CMOS 0V to Vcc
- Tx/Rx impedance:	1 ΜΩ
- Baud rate:	57600

#### Built-in Test Equipment (BITE) output

- Format:	CMOS 0V to Vcc
- Load impedance:	1 ΜΩ
- Logic:	0 = Normal operation
	1 = Alarm

# Power Input

- Operating:	<120 mW
- Warmup:	<140 mW
- Input Voltage (Vcc):	$3.3 \pm 0.1  VDC$

### PHYSICAL SPECIFICATIONS

- Size:	1.6" x 1.39" x 0.45"
- Weight:	<35 g
- MTBF:	>100.000 hours

## **ENVIRONMENTAL SPECIFICATIONS**

#### Operating:

- Operating temperature:	-10°C to +35°
- Maximum frequency change	

 Maximum frequency change over operating temp range (max. rate of change 0.5°C/minute):

5°C/minuteJ: ±5x10

 Frequency change over allowable input voltage range: ±5x10<sup>-10</sup>

±4x10<sup>-10</sup>

#### **ENVIRONMENTAL SPECIFICATIONS (Continued)**

[≼2.0 Gauss]: ±9x10-¹¹/Gauss

- Radiated emissions: Compliant to FCC part 15, Class B, when mounted properly onto host PCB

- Vibration: Maintains lock under MIL-STD-810, method 514.5, procedure 1, 7.7 grms

- Humidity: 0 to 95% RH per MIL-STD-810, method 507.4

#### Storage and Transport (non-operating):

- Temperature:	-55°C to +40°C
- Shock (1 ms half-sine):	1000 g
- Vibration:	MIL-STD-810, method 514.5, procedure 1, 7.7 grms

#### PERFORMANCE PARAMETERS

#### Stability (Allan Deviation)

- Magnetic sensitivity

#### ΔDFV

ADLI	
TAU = 1 sec	2.5x10 <sup>-10</sup>
TAU = 10 sec	8x10 <sup>-11</sup>
TAU = 100 sec	2.5x10 <sup>-11</sup>
TAU = 1000 sec	8x10 <sup>-12</sup>

### RF Output Phase Noise (SSB)

1 Hz	<-53 dBc/Hz
10 Hz	<-73 dBc/Hz
100 Hz	<-116 dBc/Hz
1000 Hz	<-131 dBc/Hz
10000 Hz	<-138 dBc/Hz
100 000 11-	. 1/0 - 10 - /11-

### Frequency Accuracy

- Maximum offset at shipment:	±5x10 <sup>-11</sup>	
- Maximum retrace (48 hrs off):	±5x10 <sup>-10</sup>	
- Aging, monthly*:	<9x10 <sup>-10</sup> typical	
- Aging, yearly*:	<1x10 <sup>-8</sup> typical	
- 1 PPS Sync.:	±100 ns	
(*After 30 days of continuous operation)		

#### **Digital Tuning**

- Range:	±2x10 <sup>-8</sup>
- Resolution:	1x10-12

# Analog Tuning

- Range:	±2.2x10 <sup>-8</sup>
- Resolution:	1x10 <sup>-11</sup>
- Input:	0-2.5V into 100 kΩ

#### Warm-up Time <180 s

#### Solder

Hand solder using 63/37 Tin/Lead Solder with maximum soldering tip of 329°C (625°F)



**Microsemi Corporate Headquarters** One Enterprise, Aliso Viejo, CA 92656 USA

Within the USA: +1 (800) 713-4113 Outside the USA: +1 (949) 380-6100 Sales: +1 (949) 380-6136 Fax: +1 (949) 215-4996

E-mail: sales.support@microsemi.com

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